

Features

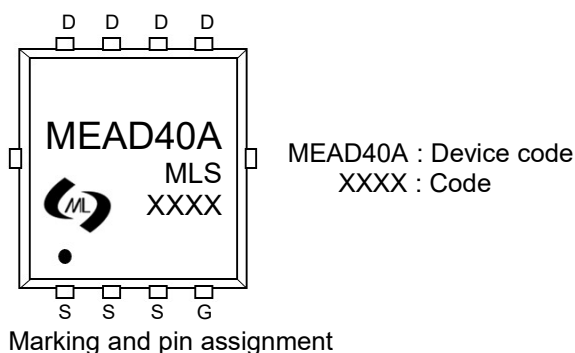
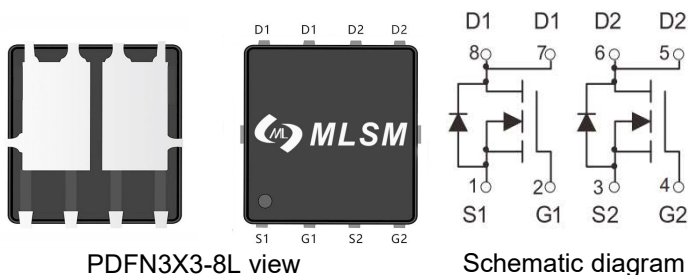
- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

Application

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

Product Summary

V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
30V	8mΩ@10V	40A
	13mΩ@4.5V	



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter		Rating	Unit
Common Ratings (TC=25°C Unless Otherwise Noted)				
V _{DS}	Drain-Source Breakdown Voltage		30	V
V _{GS}	Gate-Source Voltage		±20	V
T _J	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-55 to 150	°C
I _S	Diode Continuous Forward Current	Tc=25°C	40	A
Mounted on Large Heat Sink				
I _{DM}	Pulse Drain Current Tested	Tc=25°C	120	A
I _D	Continuous Drain Current	Tc=25°C	40	A
P _D	Maximum Power Dissipation	Tc=25°C	42	W
R _{θJA}	Thermal Resistance Junction-Ambient		60	°C/W

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MEAD40A	PDFN3X3-8L	MEAD40A	5,000	10,000	70,000	13"reel

Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	30	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =30V, V _{GS} =0V	--	--	1.0	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	1.5	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =20A	--	6	8	mΩ
		V _{GS} =4.5V, I _D =15A	--	9	13	mΩ

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)

C _{ISS}	Input Capacitance	V _{DS} =15V, V _{GS} =0V, f=1MHz	--	1300	--	pF
C _{OSS}	Output Capacitance		--	180	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	110	--	pF

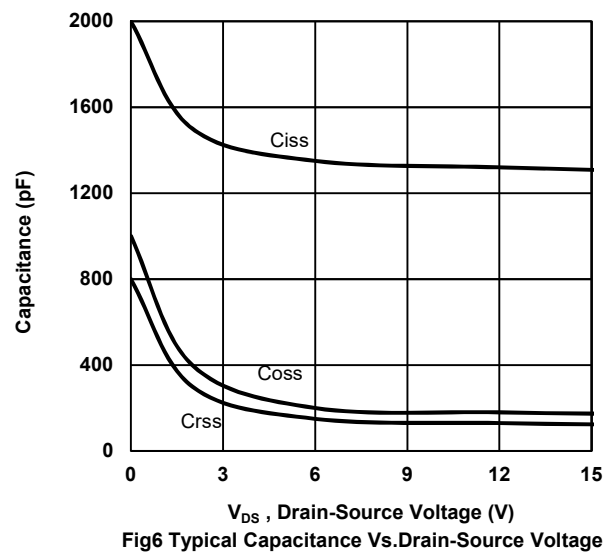
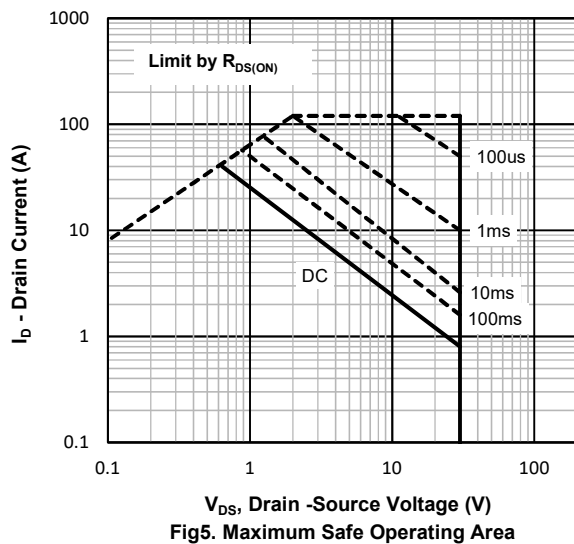
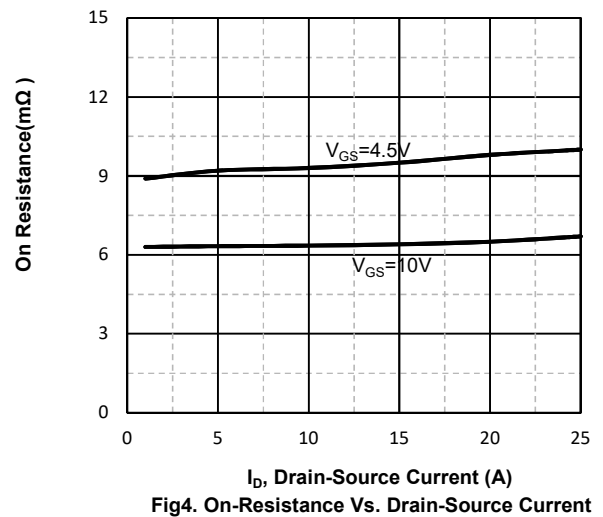
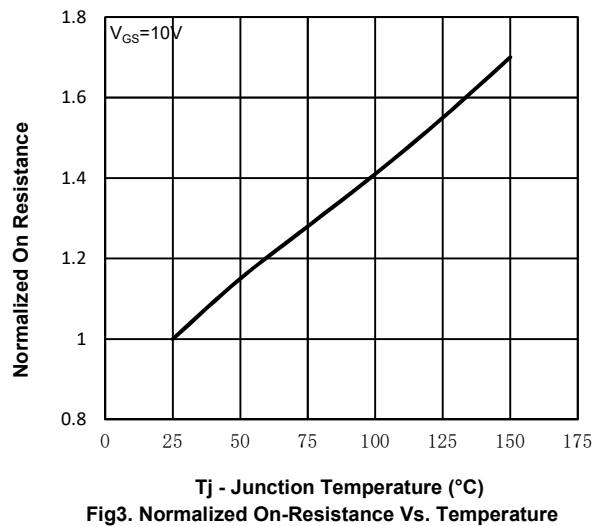
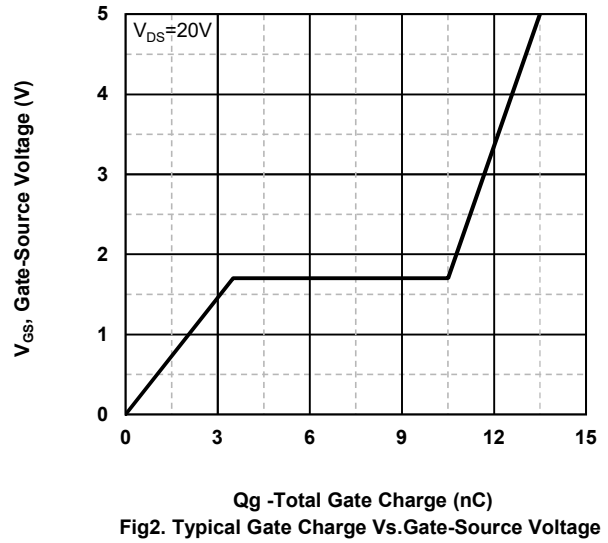
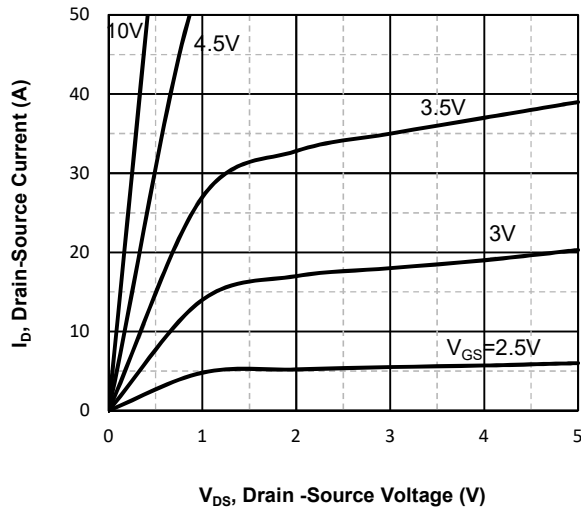
Switching Characteristics

Q _g	Total Gate Charge	V _{DS} =20V, I _D =20A, V _{GS} =4.5V	--	14	--	nC
Q _{gs}	Gate Source Charge		--	3.5	--	nC
Q _{gd}	Gate Drain Charge		--	7	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =12V, I _D =20A, V _{GS} =10V, R _G =3.3Ω	--	5	--	nS
t _r	Turn-on Rise Time		--	12	--	nS
t _{d(off)}	Turn-Off Delay Time		--	27	--	nS
t _f	Turn-Off Fall Time		--	10	--	nS

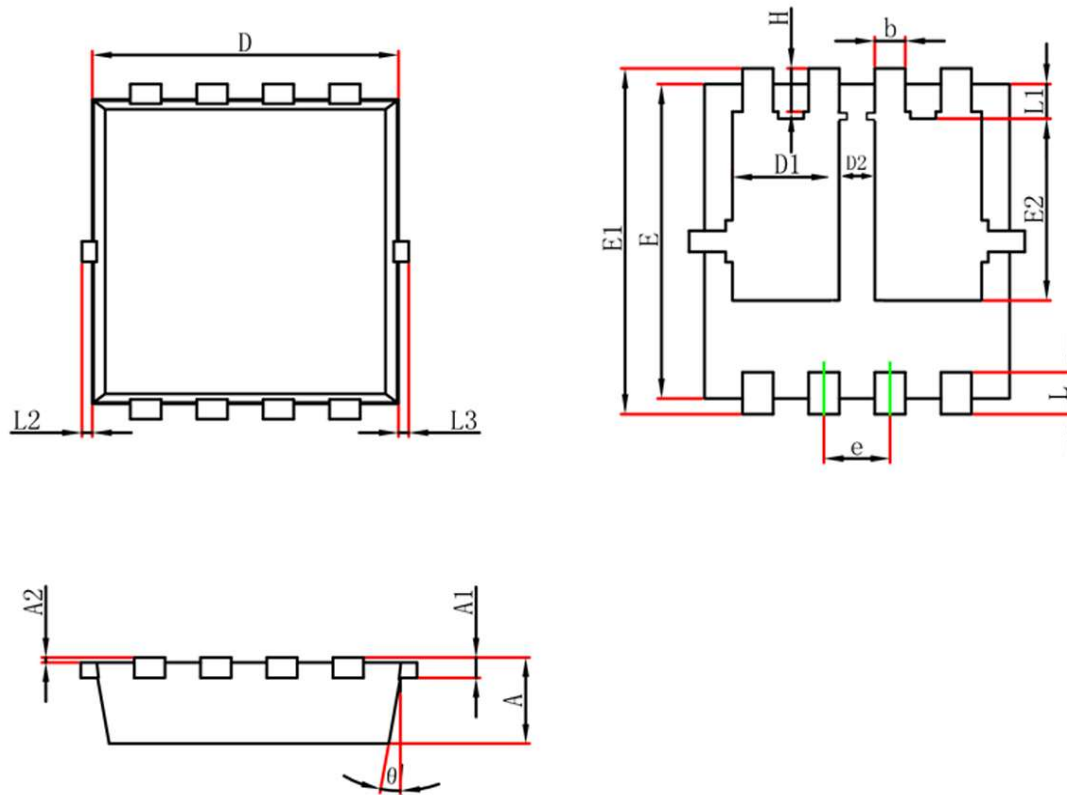
Source- Drain Diode Characteristics

V _{SD}	Forward on voltage	T _J =25°C, I _S =20A	--	--	1.2	V
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Typical Operating Characteristics



PDFN3X3-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.750	0.850	0.030	0.034
A1	0.152 REF.		0.006 REF.	
A2	0~0.05		0~0.002	
D	3.050	3.150	0.121	0.125
D1	0.985	1.085	0.039	0.043
D2	0.330	0.430	0.013	0.017
E	2.950	3.050	0.117	0.121
E1	3.250	3.350	0.129	0.132
E2	1.685	1.785	0.067	0.071
b	0.250	0.350	0.010	0.014
e	0.600	0.700	0.024	0.028
L	0.350	0.450	0.014	0.018
L1	0.280	0.380	0.011	0.015
L2	0~0.100		0~0.004	
L3	0~0.100		0~0.004	
H	0.350	0.450	0.014	0.018
θ	9°	13°	10°	12°